

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC24M00A Series

THREE TERMINAL LOW DROPOUT VOLTAGE REGULATOR

DESCRIPTION

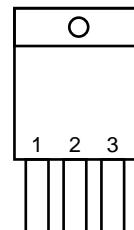
μ PC24M00A Series are low dropout regulators which have 500 mA capable for output current.

These ICs are built-in the saturation protection circuit of the output transistor.

FEATURES

- Built-in the saturation protection circuit of the output transistor.
- The capability of output current is 500 mA.
- High accuracy of output voltage.
 $|\Delta V_o| \leq \pm 2\% \text{ (} T_J = 25^\circ\text{C)}$
 $|\Delta V_o| \leq \pm 3\% \text{ (} 0^\circ\text{C} \leq T_J \leq 125^\circ\text{C)}$
- Low dropout voltage.
 $V_{DIF} \leq 1\text{ V}$ ($I_o \leq 500\text{ mA}$, $T_J \leq 125^\circ\text{C}$)
- Built-in overcurrent protection circuit, thermal shut-down circuit.
- Built-in Safe Operating Area protection circuit.
- Compatible for μ PC24M00 Series.

CONNECTION DIAGRAM (TOP VIEW)

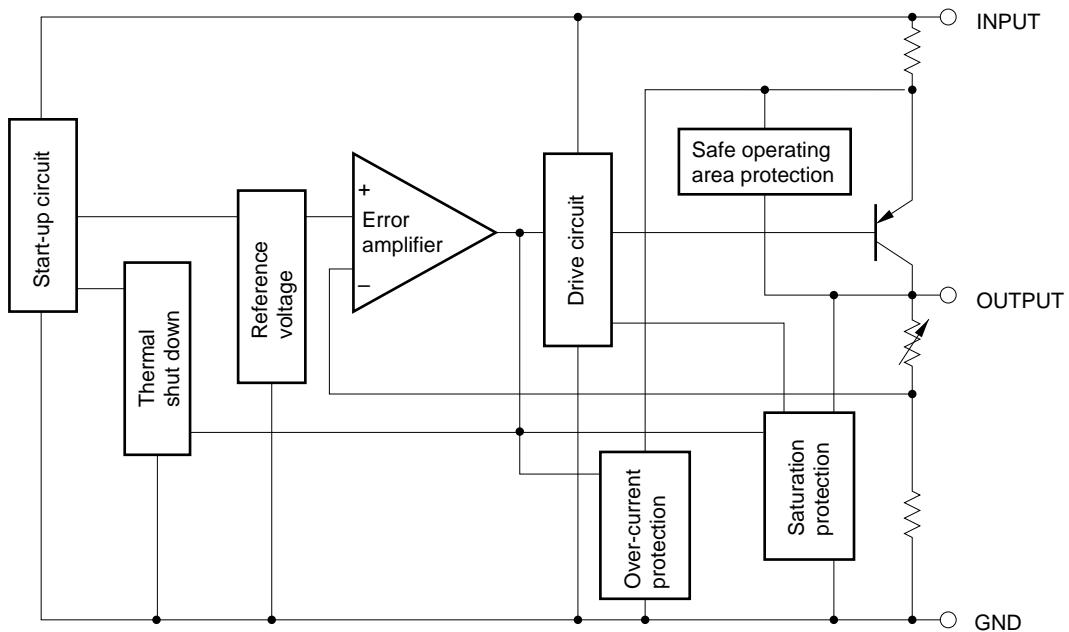


1 : INPUT
2 : GND
3 : OUTPUT

ORDERING INFORMATION

Output Voltage	Type Number	Package
5 V	μ PC24M05AHF	MP-45G (Isolated TO-220)
6 V	μ PC24M06AHF	
7 V	μ PC24M07AHF	
8 V	μ PC24M08AHF	
9 V	μ PC24M09AHF	
10 V	μ PC24M10AHF	
12 V	μ PC24M12AHF	
15 V	μ PC24M15AHF	
18 V	μ PC24M18AHF	

BLOCK DIAGRAM

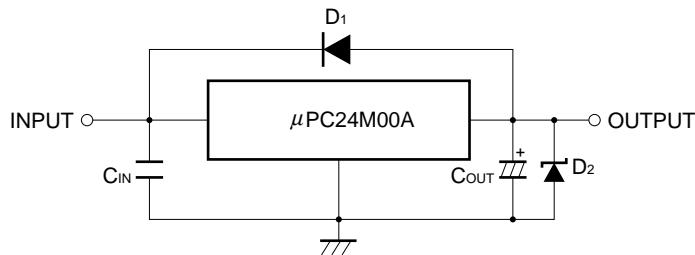


ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, Unless otherwise specified.)

PARAMETER	SYMBOL	RATING	UNIT
Input Voltage	V_{IN}	36	V
Internal Power Dissipation	P_T	15 Note	W
Operating Ambient Temperature Range	T_A	-20 to +85	$^\circ\text{C}$
Operating Junction Temperature Range	T_J	-20 to +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ\text{C}$
Thermal Resistance (Junction to Case)	$R_{th(J-C)}$	7.0	$^\circ\text{C}/\text{W}$
Thermal Resistance (Junction to Ambient)	$R_{th(J-A)}$	65	$^\circ\text{C}/\text{W}$

Note Internally limited.

TYPICAL CONNECTION



C_{IN} : 0.1 to 0.47 μF .

C_{OUT} : More than 47 μF .

D₁ : Need for $V_o > V_{IN}$.

D₂ : Need for $V_o < \text{GND}$.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TYPE NUMBER	MIN.	TYP.	MAX.	UNIT
Input Voltage	V_{IN}	μ PC24M05AHF	6	9	20	V
		μ PC24M06AHF	7	10	21	
		μ PC24M07AHF	8	11	22	
		μ PC24M08AHF	9	13	23	
		μ PC24M09AHF	10	14	24	
		μ PC24M10AHF	11	15	25	
		μ PC24M12AHF	13	18	27	
		μ PC24M15AHF	16	22	27	
		μ PC24M18AHF	19	25	28	
Output Current	I_O	All	0		500	mA
Operating Ambient Temperature Range	T_A	All	-20		+85	$^\circ\text{C}$
Operating Junction Temperature Range	T_J	All	-20		+125	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

 μ PC24M05A ($V_{IN} = 9$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V_o	4.9	5.0	5.1	V	
		4.85		5.15		$6 \text{ V} \leq V_{IN} \leq 20 \text{ V}$, $5 \text{ mA} \leq I_o \leq 350 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
		4.85		5.15		$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Line Regulation	REG_{IN}		5	50	mV	$6.5 \text{ V} \leq V_{IN} \leq 20 \text{ V}$
Load Regulation	REG_L		3	25	mV	$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$
Quiescent Current	I_{BIAS}		2.3	3.2	mA	$I_o = 0$
			7	30		$I_o = 500 \text{ mA}$
Start-up Current	$I_{BIAS(S)}$			15	mA	$V_{IN} = 4.5 \text{ V}$, $I_o = 0 \text{ mA}$
				45		$V_{IN} = 4.5 \text{ V}$, $I_o = 500 \text{ mA}$
Quiescent Current Change	ΔI_{BIAS}			10	mA	$6.5 \text{ V} \leq V_{IN} \leq 20 \text{ V}$, $I_o = 500 \text{ mA}$
Output Noise Voltage	V_n		90		μV_{rms}	$10 \text{ Hz} \leq f \leq 100 \text{ kHz}$
Ripple Rejection	$R \cdot R$	55	60		dB	$f = 120 \text{ Hz}$, $6.5 \text{ V} \leq V_{IN} \leq 16.5 \text{ V}$
Dropout Voltage	V_{DIF}		0.5	1.0	V	$I_o = 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Short Circuit Current	I_{Oshort}		0.6		A	$V_{IN} = 20 \text{ V}$
Peak Output Current	I_{Opeak}	0.75	1.0	1.63	A	$V_{IN} = 9 \text{ V}$
Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T$		0.2		mV/C	$I_o = 5 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$

 μ PC24M06A ($V_{IN} = 10$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V_o	5.88	6.0	6.12	V	
		5.82		6.18		$7 \text{ V} \leq V_{IN} \leq 21 \text{ V}$, $5 \text{ mA} \leq I_o \leq 350 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
		5.82		6.18		$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Line Regulation	REG_{IN}		6	60	mV	$7.5 \text{ V} \leq V_{IN} \leq 21 \text{ V}$
Load Regulation	REG_L		4	30	mV	$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$
Quiescent Current	I_{BIAS}		2.3	3.2	mA	$I_o = 0$
			7	30		$I_o = 500 \text{ mA}$
Start-up Current	$I_{BIAS(S)}$			15	mA	$V_{IN} = 5.5 \text{ V}$, $I_o = 0 \text{ mA}$
				45		$V_{IN} = 5.5 \text{ V}$, $I_o = 500 \text{ mA}$
Quiescent Current Change	ΔI_{BIAS}			10	mA	$7.5 \text{ V} \leq V_{IN} \leq 21 \text{ V}$, $I_o = 500 \text{ mA}$
Output Noise Voltage	V_n		110		μV_{rms}	$10 \text{ Hz} \leq f \leq 100 \text{ kHz}$
Ripple Rejection	$R \cdot R$	53	58		dB	$f = 120 \text{ Hz}$, $7.5 \text{ V} \leq V_{IN} \leq 17.5 \text{ V}$
Dropout Voltage	V_{DIF}		0.5	1.0	V	$I_o = 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Short Circuit Current	I_{Oshort}		0.6		A	$V_{IN} = 21 \text{ V}$
Peak Output Current	I_{Opeak}	0.75	1.0	1.63	A	$V_{IN} = 10 \text{ V}$
Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T$		-0.4		mV/C	$I_o = 5 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$

μ PC24M07A ($V_{IN} = 11$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V_o	6.86	7.0	7.14	V	
		6.79		7.21		8 V ≤ V_{IN} ≤ 22 V, 5 mA ≤ I_o ≤ 350 mA, 0 °C ≤ T_J ≤ 125 °C
		6.79		7.21		5 mA ≤ I_o ≤ 500 mA, 0 °C ≤ T_J ≤ 125 °C
Line Regulation	REG_{IN}		7	70	mV	8.5 V ≤ V_{IN} ≤ 22 V
Load Regulation	REG_L		4	35	mV	5 mA ≤ I_o ≤ 500 mA
Quiescent Current	I_{BIAS}		2.3	3.2	mA	$I_o = 0$
			7	30		$I_o = 500$ mA
Start-up Current	$I_{BIAS(S)}$			15	mA	$V_{IN} = 6.5$ V, $I_o = 0$ mA
				45		$V_{IN} = 6.5$ V, $I_o = 500$ mA
Quiescent Current Change	ΔI_{BIAS}			10	mA	8.5 V ≤ V_{IN} ≤ 22 V, $I_o = 500$ mA
Output Noise Voltage	V_n		130		μV_{rms}	10 Hz ≤ f ≤ 100 kHz
Ripple Rejection	R·R	52	57		dB	f = 120 Hz, 8.5 V ≤ V_{IN} ≤ 18.5 V
Dropout Voltage	V_{DIF}		0.5	1.0	V	$I_o = 500$ mA, 0 °C ≤ T_J ≤ 125 °C
Short Circuit Current	I_{Oshort}		0.6		A	$V_{IN} = 22$ V
Peak Output Current	I_{Opeak}	0.75	1.0	1.63	A	$V_{IN} = 11$ V
Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T$		0.4		mV/°C	$I_o = 5$ mA, 0 °C ≤ T_J ≤ 125 °C

 μ PC24M08A ($V_{IN} = 13$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V_o	7.85	8.0	8.15	V	
		7.75		8.25		9 V ≤ V_{IN} ≤ 23 V, 5 mA ≤ I_o ≤ 350 mA, 0 °C ≤ T_J ≤ 125 °C
		7.75		8.25		5 mA ≤ I_o ≤ 500 mA, 0 °C ≤ T_J ≤ 125 °C
Line Regulation	REG_{IN}		8	80	mV	9.5 V ≤ V_{IN} ≤ 23 V
Load Regulation	REG_L		5	40	mV	5 mA ≤ I_o ≤ 500 mA
Quiescent Current	I_{BIAS}		2.3	3.2	mA	$I_o = 0$
			7	30		$I_o = 500$ mA
Start-up Current	$I_{BIAS(S)}$			15	mA	$V_{IN} = 7.5$ V, $I_o = 0$ mA
				45		$V_{IN} = 7.5$ V, $I_o = 500$ mA
Quiescent Current Change	ΔI_{BIAS}			10	mA	9.5 V ≤ V_{IN} ≤ 23 V, $I_o = 500$ mA
Output Noise Voltage	V_n		150		μV_{rms}	10 Hz ≤ f ≤ 100 kHz
Ripple Rejection	R·R	51	56		dB	f = 120 Hz, 9.5 V ≤ V_{IN} ≤ 19.5 V
Dropout Voltage	V_{DIF}		0.5	1.0	V	$I_o = 500$ mA, 0 °C ≤ T_J ≤ 125 °C
Short Circuit Current	I_{Oshort}		0.5		A	$V_{IN} = 23$ V
Peak Output Current	I_{Opeak}	0.74	1.0	1.62	A	$V_{IN} = 13$ V
Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T$		0.8		mV/°C	$I_o = 5$ mA, 0 °C ≤ T_J ≤ 125 °C

μ PC24M09A ($V_{IN} = 14$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V _o	8.82	9.0	9.18	V	
		8.73		9.27		10 V ≤ V _{IN} ≤ 24 V, 5 mA ≤ I _o ≤ 350 mA, 0 °C ≤ T _J ≤ 125 °C
		8.73		9.27		5 mA ≤ I _o ≤ 500 mA, 0 °C ≤ T _J ≤ 125 °C
Line Regulation	REG _{IN}		9	90	mV	10.5 V ≤ V _{IN} ≤ 24 V
Load Regulation	REG _L		5	45	mV	5 mA ≤ I _o ≤ 500 mA
Quiescent Current	I _{BIAS}		2.4	3.2	mA	I _o = 0
			7	30		I _o = 500 mA
Start-up Current	I _{BIAS(S)}			15	mA	V _{IN} = 8.5 V, I _o = 0 mA
				45		V _{IN} = 8.5 V, I _o = 500 mA
Quiescent Current Change	ΔI _{BIAS}			10	mA	10.5 V ≤ V _{IN} ≤ 24 V, I _o = 500 mA
Output Noise Voltage	V _n		170		μV _{rms}	10 Hz ≤ f ≤ 100 kHz
Ripple Rejection	R·R	50	55		dB	f = 120 Hz, 10.5 V ≤ V _{IN} ≤ 20.5 V
Dropout Voltage	V _{DIF}		0.5	1.0	V	I _o = 500 mA, 0 °C ≤ T _J ≤ 125 °C
Short Circuit Current	I _{Oshort}		0.5		A	V _{IN} = 24 V
Peak Output Current	I _{Opeak}	0.74	1.0	1.62	A	V _{IN} = 14 V
Temperature Coefficient of Output Voltage	ΔV _o /ΔT		1.0		mV/°C	I _o = 5 mA, 0 °C ≤ T _J ≤ 125 °C

 μ PC24M10A ($V_{IN} = 15$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V _o	9.8	10	10.2	V	
		9.7		10.3		11 V ≤ V _{IN} ≤ 25 V, 5 mA ≤ I _o ≤ 350 mA, 0 °C ≤ T _J ≤ 125 °C
		9.7		10.3		5 mA ≤ I _o ≤ 500 mA, 0 °C ≤ T _J ≤ 125 °C
Line Regulation	REG _{IN}		10	100	mV	11.5 V ≤ V _{IN} ≤ 25 V
Load Regulation	REG _L		6	50	mV	5 mA ≤ I _o ≤ 500 mA
Quiescent Current	I _{BIAS}		2.4	3.2	mA	I _o = 0
			7	30		I _o = 500 mA
Start-up Current	I _{BIAS(S)}			15	mA	V _{IN} = 9.5 V, I _o = 0 mA
				45		V _{IN} = 9.5 V, I _o = 500 mA
Quiescent Current Change	ΔI _{BIAS}			10	mA	11.5 V ≤ V _{IN} ≤ 25 V, I _o = 500 mA
Output Noise Voltage	V _n		190		μV _{rms}	10 Hz ≤ f ≤ 100 kHz
Ripple Rejection	R·R	49	54		dB	f = 120 Hz, 11.5 V ≤ V _{IN} ≤ 21.5 V
Dropout Voltage	V _{DIF}		0.5	1.0	V	I _o = 500 mA, 0 °C ≤ T _J ≤ 125 °C
Short Circuit Current	I _{Oshort}		0.4		A	V _{IN} = 25 V
Peak Output Current	I _{Opeak}	0.74	1.0	1.62	A	V _{IN} = 15 V
Temperature Coefficient of Output Voltage	ΔV _o /ΔT		1.6		mV/°C	I _o = 5 mA, 0 °C ≤ T _J ≤ 125 °C

μ PC24M12A ($V_{IN} = 18$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V_o	11.75	12	12.25	V	
		11.65		12.35		$13 \text{ V} \leq V_{IN} \leq 27 \text{ V}$, $5 \text{ mA} \leq I_o \leq 350 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
		11.65		12.35		$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Line Regulation	REG_{IN}		12	120	mV	$14 \text{ V} \leq V_{IN} \leq 27 \text{ V}$
Load Regulation	REG_L		7	60	mV	$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$
Quiescent Current	I_{BIAS}		2.4	3.2	mA	$I_o = 0$
			8	30		$I_o = 500 \text{ mA}$
Start-up Current	$I_{BIAS(S)}$			15	mA	$V_{IN} = 11.5 \text{ V}$, $I_o = 0 \text{ mA}$
				45		$V_{IN} = 11.5 \text{ V}$, $I_o = 500 \text{ mA}$
Quiescent Current Change	ΔI_{BIAS}			10	mA	$14 \text{ V} \leq V_{IN} \leq 27 \text{ V}$, $I_o = 500 \text{ mA}$
Output Noise Voltage	V_n		230		μV_{rms}	$10 \text{ Hz} \leq f \leq 100 \text{ kHz}$
Ripple Rejection	R·R	47	52		dB	$f = 120 \text{ Hz}$, $14 \text{ V} \leq V_{IN} \leq 24 \text{ V}$
Dropout Voltage	V_{DIF}		0.5	1.0	V	$I_o = 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Short Circuit Current	I_{Oshort}		0.4		A	$V_{IN} = 27 \text{ V}$
Peak Output Current	I_{Opeak}	0.73	1.0	1.61	A	$V_{IN} = 18 \text{ V}$
Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T$		0.7		$\text{mV}/^{\circ}\text{C}$	$I_o = 5 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$

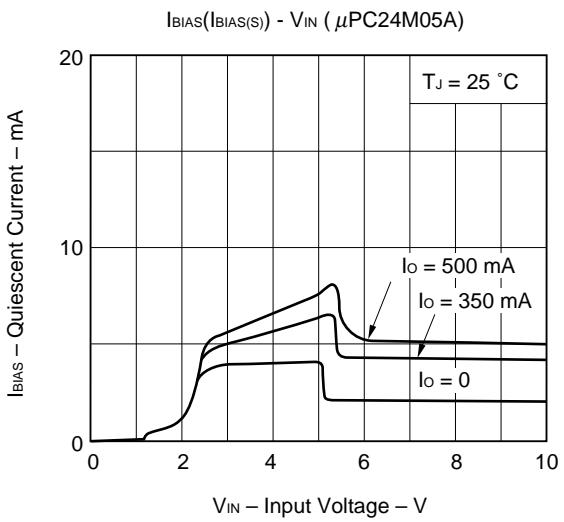
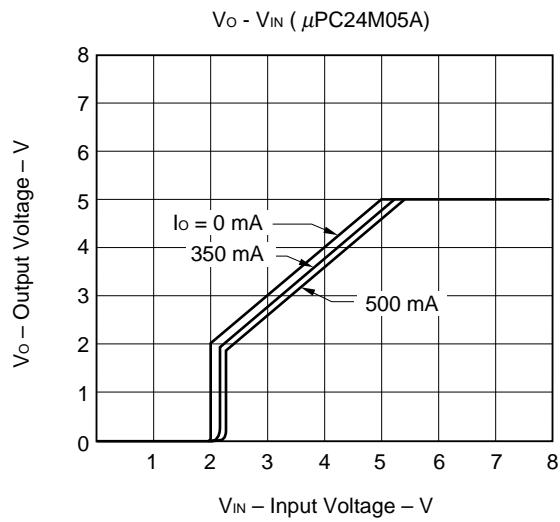
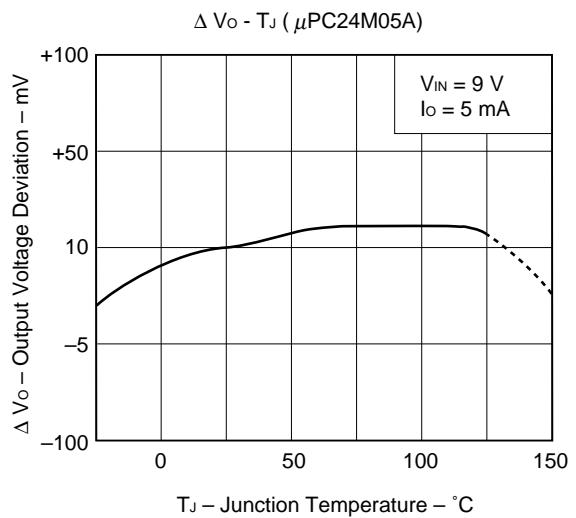
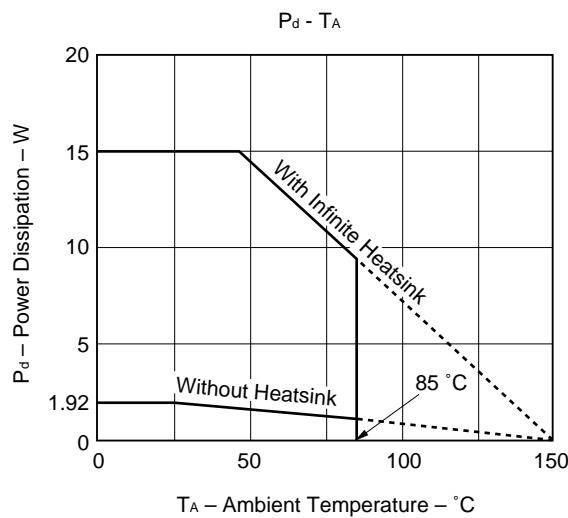
 μ PC24M15A ($V_{IN} = 22$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V_o	14.7	15	15.3	V	
		14.55		15.45		$16 \text{ V} \leq V_{IN} \leq 27 \text{ V}$, $5 \text{ mA} \leq I_o \leq 350 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
		14.55		15.45		$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Line Regulation	REG_{IN}		15	150	mV	$17 \text{ V} \leq V_{IN} \leq 27 \text{ V}$
Load Regulation	REG_L		9	75	mV	$5 \text{ mA} \leq I_o \leq 500 \text{ mA}$
Quiescent Current	I_{BIAS}		2.5	3.2	mA	$I_o = 0$
			8	30		$I_o = 500 \text{ mA}$
Start-up Current	$I_{BIAS(S)}$			15	mA	$V_{IN} = 14.5 \text{ V}$, $I_o = 0 \text{ mA}$
				45		$V_{IN} = 14.5 \text{ V}$, $I_o = 500 \text{ mA}$
Quiescent Current Change	ΔI_{BIAS}			10	mA	$17 \text{ V} \leq V_{IN} \leq 27 \text{ V}$, $I_o = 500 \text{ mA}$
Output Noise Voltage	V_n		290		μV_{rms}	$10 \text{ Hz} \leq f \leq 100 \text{ kHz}$
Ripple Rejection	R·R	46	51		dB	$f = 120 \text{ Hz}$, $17 \text{ V} \leq V_{IN} \leq 27 \text{ V}$
Dropout Voltage	V_{DIF}		0.5	1.0	V	$I_o = 500 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$
Short Circuit Current	I_{Oshort}		0.4		A	$V_{IN} = 27 \text{ V}$
Peak Output Current	I_{Opeak}	0.72	1.0	1.6	A	$V_{IN} = 22 \text{ V}$
Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T$		1.6		$\text{mV}/^{\circ}\text{C}$	$I_o = 5 \text{ mA}$, $0 \text{ }^{\circ}\text{C} \leq T_J \leq 125 \text{ }^{\circ}\text{C}$

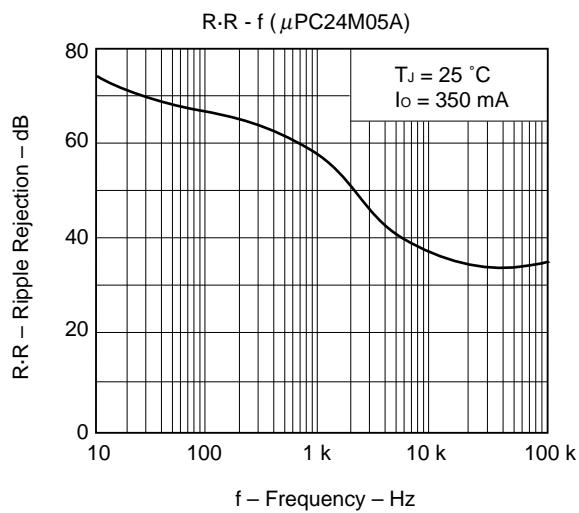
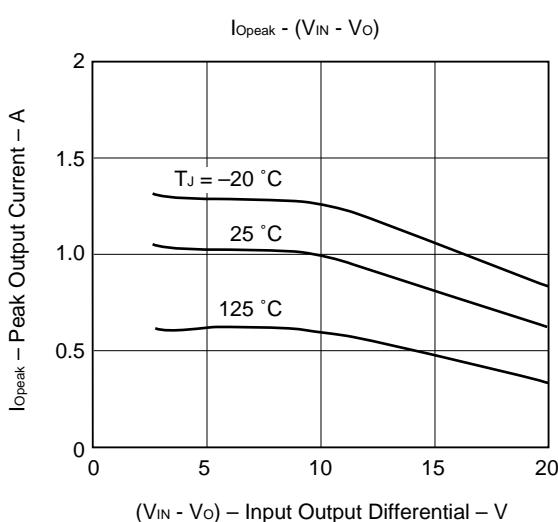
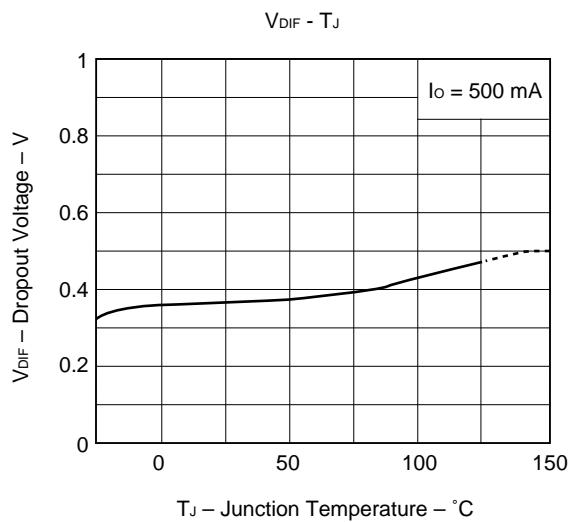
μ PC24M18A ($V_{IN} = 25$ V, $I_o = 350$ mA, $T_J = 25$ °C, Unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Output Voltage	V _o	17.64	18	18.36	V	
		17.46		18.54		19 V ≤ V _{IN} ≤ 28 V, 5 mA ≤ I _o ≤ 350 mA, 0 °C ≤ T _J ≤ 125 °C
		17.46		18.54		5 mA ≤ I _o ≤ 500 mA, 0 °C ≤ T _J ≤ 125 °C
Line Regulation	REG _{IN}		18	180	mV	20 V ≤ V _{IN} ≤ 28 V
Load Regulation	REG _L		11	90	mV	5 mA ≤ I _o ≤ 500 mA
Quiescent Current	I _{BIAS}		2.5	3.2	mA	I _o = 0
			8	30		I _o = 500 mA
Start-up Current	I _{BIAS(S)}			15	mA	V _{IN} = 17.5 V, I _o = 0 mA
				45		V _{IN} = 17.5 V, I _o = 500 mA
Quiescent Current Change	ΔI _{BIAS}			10	mA	20 V ≤ V _{IN} ≤ 28 V, I _o = 500 mA
Output Noise Voltage	V _n		350		μV _{rms}	10 Hz ≤ f ≤ 100 kHz
Ripple Rejection	R·R	44	49		dB	f = 120 Hz, 20 V ≤ V _{IN} ≤ 28 V
Dropout Voltage	V _{DIF}		0.5	1.0	V	I _o = 500 mA, 0 °C ≤ T _J ≤ 125 °C
Short Circuit Current	I _{Oshort}		0.4		A	V _{IN} = 28 V
Peak Output Current	I _{Opeak}	0.72	1.0	1.6	A	V _{IN} = 25 V
Temperature Coefficient of Output Voltage	ΔV _o /ΔT		2.2		mV/°C	I _o = 5 mA, 0 °C ≤ T _J ≤ 125 °C

TYPICAL CHARACTERISTICS



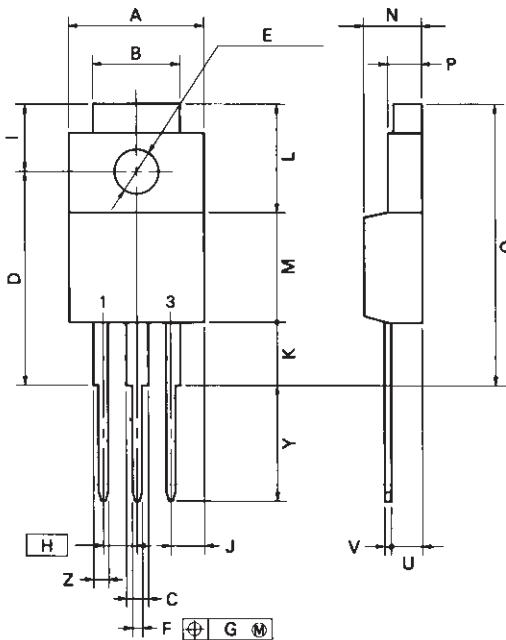
TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS (Unit: mm)

 μ PC24M00AHF Series

3PIN PLASTIC SIP (MP-45G)



P3HF-254B-1

NOTE

Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	10.4 MAX.	0.410 MAX.
B	7.0	0.276
C	1.2 MIN.	0.047 MIN.
D	17.0 ^{±0.3}	0.669 ^{+0.013} _{-0.012}
E	φ3.3 ^{±0.2}	φ0.130 ^{+0.008}
F	0.75 ^{±0.10}	0.030 ^{+0.004} _{-0.006}
G	0.25	0.010
H	2.54 (T.P.)	0.100 (T.P.)
I	5.0 ^{±0.3}	0.197 ^{+0.012}
J	2.66 MAX.	0.105 MAX.
K	4.8 MIN.	0.188 MIN.
L	8.5	0.335
M	8.5	0.335
N	4.5 ^{±0.2}	0.177 ^{+0.008}
P	2.8 ^{±0.2}	0.110 ^{+0.008} _{-0.008}
Q	22.4 MAX.	0.882 MAX.
R	2.4 ^{±0.6}	0.094 ^{+0.021} _{-0.020}
S	0.65 ^{±0.10}	0.026 ^{+0.004} _{-0.006}
T	8.9 ^{±0.7}	0.350 ^{+0.028}
Z	1.0 MIN.	0.039 MIN.

RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF THROUGH HOLE MOUNT DEVICE

μ PC24M00AHF Series

Soldering Process	Soldering Conditions	Symbol
Wave soldering	Solder temperature: 260 °C or below. Flow Time: 10 seconds or below.	

REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	IEI-1212
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	IEI-1207
Semiconductor device package manual	IEI-1213
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	MF-1134

[MEMO]

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While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customer must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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